

PC123XNNSZ0F **Series**

DIP 4pin Reinforced Insulation Type Photocoupler



■ Description

PC123XNNSZ0F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5kV.

CTR is 50% to 400% at input current of 5mA

■ Features

- 1. 4-pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. Current transfer ratio (CTR: MIN. 50% at I_F=5 mA, $V_{CE}=5V$)
- 4. Several CTR ranks available
- 5. Reinforced insulation type (Isolation distance : MIN.
- 6. Long creepage distance type (wide lead-form type only: MIN. 8mm)
- 7. High isolation voltage between input and output $(V_{iso}(rms):5kV)$
- 8. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC123)
- 2. Approved by BSI, BS-EN60065, file No. 7087, BS-EN60950 file No. 7409, (as model No. PC123)
- 3. Approved by SEMKO, EN60065, EN60950, (as model No. PC123)
- 4. Approved by DEMKO, EN60065, EN60950, (as model No. PC123)
- 5. Approved by NEMKO, EN60065, EN60950, (as model No. PC123)
- 6. Approved by FIMKO, EN60065, EN60950, (as model No. PC123)
- 7. Recognized by CSA file No. CA95323, (as model No. PC123)
- 8. Approved by VDE, DIN EN60747-5-2(*) (as an option), file No. 40008087 (as model No. PC123)
- 9. Package resin: UL flammability grade (94V 0)
 - (*) DIN EN60747-5-2: successor standard of DIN VDE0884.

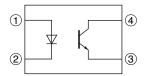
■ Applications

- 1. I/O isolation for MCUs (Micro Controller Units)
- 2. Noise suppression in switching circuits
- 3. Signal transmission between circuits of different potentials and impedances
- 4. Over voltage detection

1



■ Internal Connection Diagram

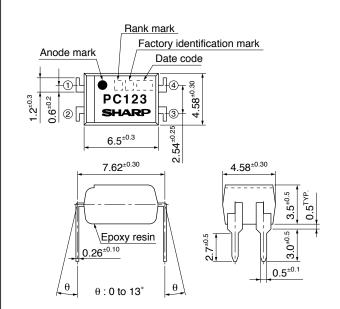


- 1 Anode
- ② Cathode
- 3 Emitter
- 4 Collector

■ Outline Dimensions

(Unit:mm)

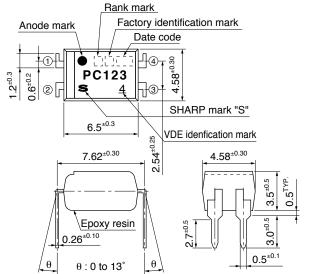
1. Through-Hole [ex. PC123XNNSZ0F]



Product mass: approx. 0.23g

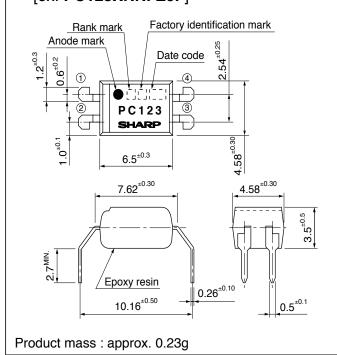
2. Through-Hole (VDE option)



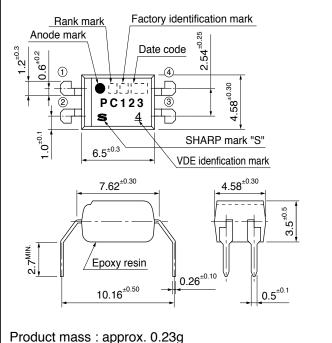


Product mass: approx. 0.23g

3. Wide Through-Hole Lead-Form [ex. **PC123XNNFZ0F**]



4. Wide Through-Hole Lead-Form (VDE option) [ex. **PC123XNYFZ0F**]

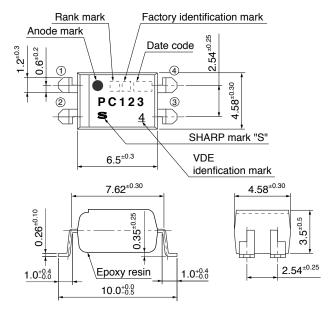


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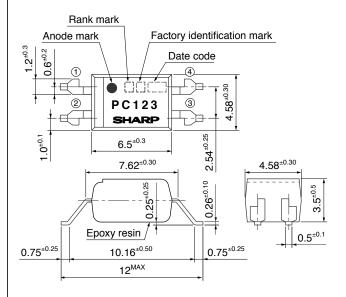
(Unit:mm)

5. SMT Gullwing Lead-Form (VDE option) [ex. **PC123XNYIP0F**]



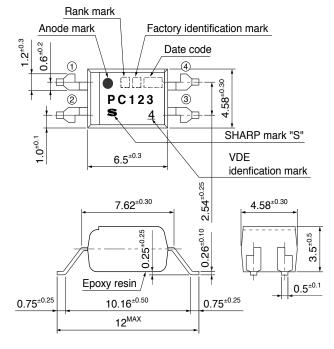
Product mass: approx. 0.22g

6. Wide SMT Gullwing Lead-Form [ex. **PC123XNNUP0F**]



Product mass: approx. 0.22g

7. Wide SMT Gullwing Lead-Form (VDE option) [ex. **PC123XNYUP0F**]



Product mass: approx. 0.22g



Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D.	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material	
no mark	Ionon	SnCu (Cu : TYP. 2%)	
	Japan		
or 🖊	Indonesia	SnBi (Bi : TYP. 2%)	
or \	China	SnCu (Cu : TYP. 2%)*	
	Cillia	SnCu (Cu : TYP. 2%)	

^{*} Up to Date code "T4" (April 2005), SnBi (Bi : TYP. 2%).

Please contact the local SHARP sales representative to see the actural status of the production.

Rank mark

Refer to the Model Line-up table.

^{**} This factory marking is for identification purpose only.



Absolute Maximum Ratings

$\blacksquare \text{ Absolute waxiiiiuiii hattiigs} \qquad \qquad (T_a=25^{\circ}\text{C})$							
Parameter	Symbol	Rating	Unit				
Forward current	I_{F}	50	mA				
*1 Peak forward current	I_{FM}	1	A				
Reverse voltage	V _R	6	V				
Power dissipation	P	70	mW				
Collector-emitter voltage		70	V				
Emitter-collector voltage	V _{ECO}	6	V				
Collector current	I_{C}	50	mA				
Collector power dissipation	P _C	150	mW				
power dissipation	P _{tot}	200	mW				
*2 Isolation voltage		5	kV				
Operating temperature		-30 to +100	°C				
Storage temperature		-55 to +125	°C				
ering temperature	T _{sol}	260	°C				
	Parameter Forward current *1 Peak forward current Reverse voltage Power dissipation Collector-emitter voltage Emitter-collector voltage Collector current Collector power dissipation power dissipation ion voltage ating temperature ge temperature	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				

^{*1} Pulse width≤100ms, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f = 60Hz

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

	(1 _a -25							
	Parameter		Symbol	Condition	MIN.	TYP.	MAX.	Unit
	Forward voltage		V_{F}	I _F =20mA	_	1.2	1.4	V
Input	Reverse current		I_R	V _R =4V	_	_	10	μΑ
	Terminal capacitance		Ct	V=0, f=1kHz	_	30	250	pF
	Collector dark current		I_{CEO}	$V_{CE}=50V, I_{F}=0$	_	_	100	nA
Output	Collector-emitter breakdown voltage		BV_{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	70	_	_	V
	Emitter-collector breakdown voltage		BV_{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	_	_	nA
	Collector current		I_{C}	$I_F=5mA, V_{CE}=5V$	2.5	_	20	mA
	Collector-emitter saturation	on voltage	V _{CE(sat)}	$I_F=20\text{mA}, I_C=1\text{mA}$	_	0.1	0.2	V
Transfer	charac- Floating capacitance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
charac-			$C_{\rm f}$	V=0, f=1MHz	_	0.6	1	pF
teristics			f_{C}	$V_{CE}=5V, I_{C}=2mA, R_{L}=100\Omega, -3dB$	_	80	_	kHz
	Dogmongo timo	Rise time	t _r	V 2V I 2m A B 1000	_	4	18	μs
	Response time	Fall time	t_{f}	$V_{CE}=2V$, $I_{C}=2mA$, $R_{L}=100\Omega$	_	3	18	μs

^{*3} For 10s



■ Model Line-up

Model No.

Lead Form	Throug	h-Hole	Wide Thro	ough-Hole		I _C [mA]
Package			(I _F =5mA,			
rackage		100pcs	/sleeve		Rank mark	$V_{CE}=5V$,
DIN		A manayya d		A 1]	$T_a=25^{\circ}C$
EN60747-5-2		Approved		Approved		1 _a =25 C)
	PC123XNNSZ0F	PC123XNYSZ0F	PC123XNNFZ0F	PC123XNYFZ0F	With or without	2.5 to 20
	PC123X1NSZ0F	PC123X1YSZ0F	PC123X1NFZ0F	PC123X1YFZ0F	L	2.5 to 7.5
Model No.	PC123X2NSZ0F	PC123X2YSZ0F	PC123X2NFZ0F	PC123X2YFZ0F	M	5 to 12.5
	PC123X5NSZ0F	PC123X5YSZ0F	PC123X5NFZ0F	PC123X5YFZ0F	N	10 to 20
	PC123X8NSZ0F	PC123X8YSZ0F	PC123X8NFZ0F	PC123X8YFZ0F	Е	5 to 10
Lead Form	SMT G	ullwing	Wide SMT	Gullwing Gullwing		Ι [Δ.]
D1			$I_{\rm C}[{\rm mA}]$			
Package		2 000p	ocs/reel		Rank mark	$(I_F=5mA, V_{CE}=5V, T_a=25^{\circ}C)$
DIN EN60747-5-2		Approved		Approved		

PC123XNNUP0F

PC123X1NUP0F

PC123X2NUP0F

PC123X5NUP0F

6

PC123X8NUP0F PC123X8YUP0F

PC123XNYUP0F

PC123X1YUP0F

PC123X2YUP0F

PC123X5YUP0F

With or without

L

M

N

Ε

2.5 to 20 2.5 to 7.5

5 to 12.5

10 to 20

5 to 10

Please contact a local SHARP sales representative to inquire about production status.

PC123XNYIP0F

PC123X1YIP0F

PC123X2YIP0F

PC123X5YIP0F

PC123X8YIP0F



Fig.1 Forward Current vs. Ambient Temperature

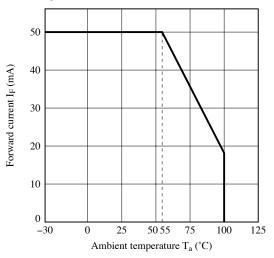


Fig.3 Collector Power Dissipation vs.
Ambient Temperature

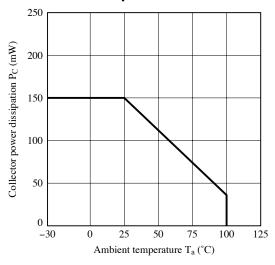


Fig.5 Peak Forward Current vs. Duty Ratio

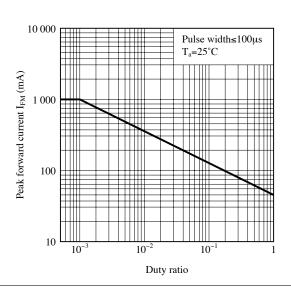


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

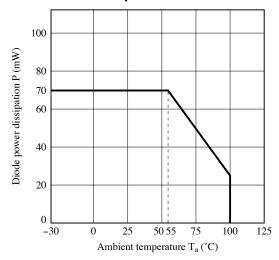


Fig.4 Total Power Dissipation vs. Ambient Temperature

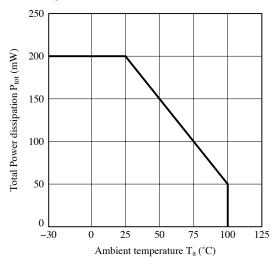


Fig.6 Forward Current vs. Forward Voltage

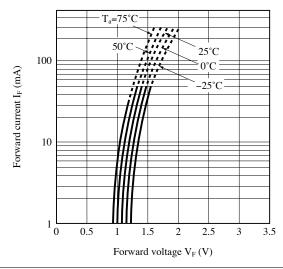




Fig.7 Current Transfer Ratio vs. Forward Current

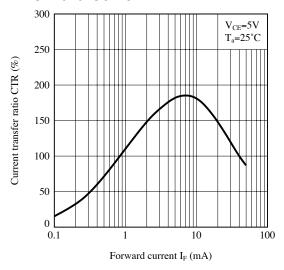


Fig.9 Relative Current Transfer Ratio vs.
Ambient Temperature

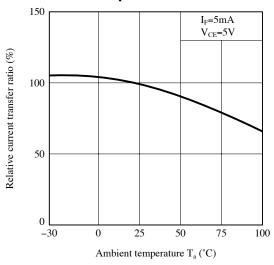


Fig.11 Collector Dark Current vs.

Ambient Temperature

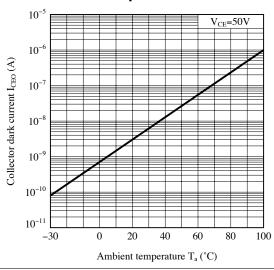


Fig.8 Collector Current vs.
Collector-emitter Voltage

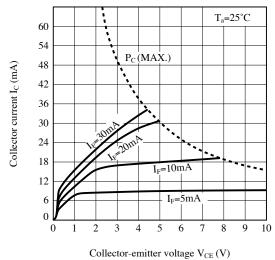


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

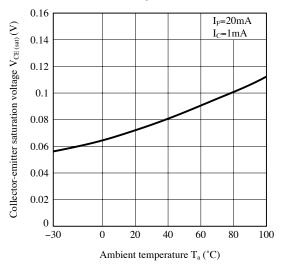


Fig.12 Response Time vs. Load Resistance

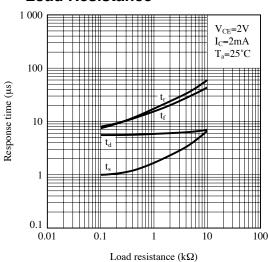




Fig.13 Test Circuit for Response Time

Please refer to the conditions in Fig.12.

Fig.14 Frequency Response

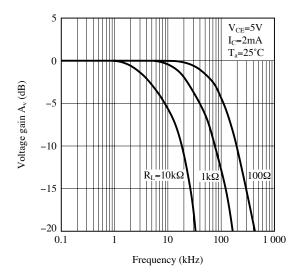
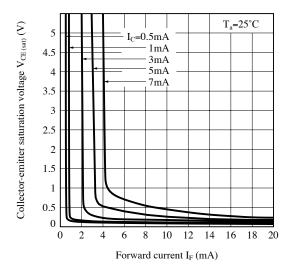


Fig.15 Collector-emitter Saturation Voltage vs. Forward Current



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1mA, CTR variation may increase.

Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

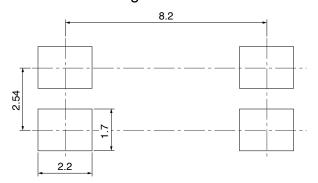
Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

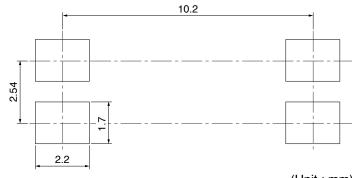
In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended foot print (reference)

SMT Gullwing lead-form



Wide SMT Gullwing lead-form



(Unit : mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

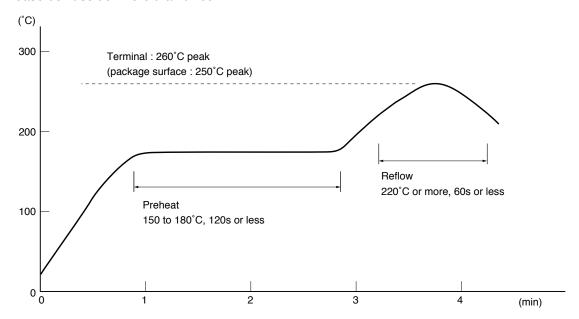
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

Sleeve package

1. Through-Hole

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

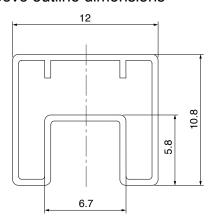
Package method

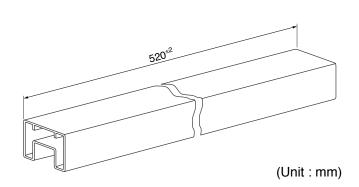
MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions





2. Wide Through-Hole

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

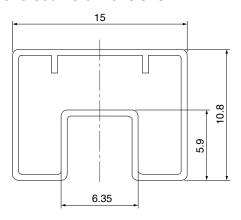
Package method

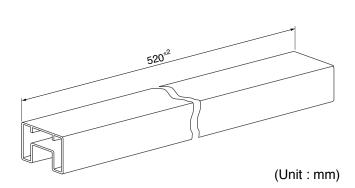
MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions







● Tape and Reel package

1. SMT Gullwing

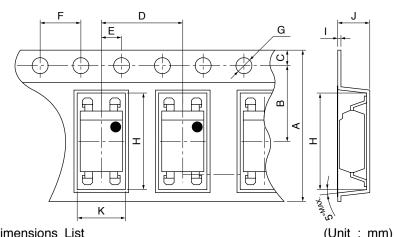
Package materials

Carrier tape : PS

Cover tape: PET (three layer system)

Reel: PS

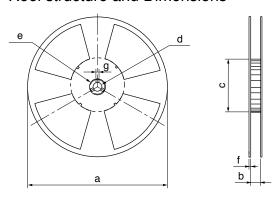
Carrier tape structure and Dimensions



Dimensions List

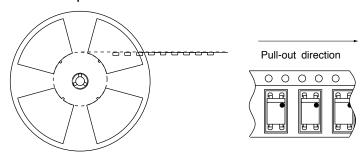
Difficition	io Liot	(Onit : min)				
A	В	С	D	Е	F	G
16.0±0.3	7.5 ^{±0.1}	1.75 ^{±0.10}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5+8:δ
Н	I	J	K			
10.4 ^{±0.1}	0.40±0.05	4.2 ^{±0.1}	5.1 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
ф330	17.5 ^{±1.5}	φ100±1	ф13.0±0.5	
e	f	g		
φ23±1	2.0±0.5	2.0±0.5		

Direction of product insertion



[Packing: 2 000pcs/reel]



2. Wide SMT Gullwing

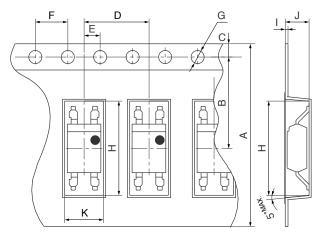
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

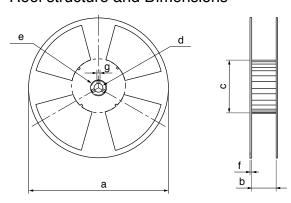
Reel: PS

Carrier tape structure and Dimensions



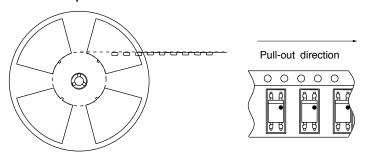
Dimension	(L	Jnit: mm)				
A	В	C	D	Е	F	G
24.0±0.3	11.5 ^{±0.1}	1.75 ^{±0.10}	8.0 ^{±0.1}	2.0±0.1	4.0±0.1	φ1.5 ^{+0.1} _{-0.0}
Н	I	J	K			
10.4+0.1	0.40+0.05	4 4 +0 1	7.1+0.1			

Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
ф330	25.5±1.5	φ100±1	φ13.0±0.5	
e	f	g		
φ23 ^{±1}	2.0±0.5	2.0±0.5		

Direction of product insertion



[Packing: 2 000pcs/reel]



■ Important Notices

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 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

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- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
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